Theories behind recurrent neural networks

Content

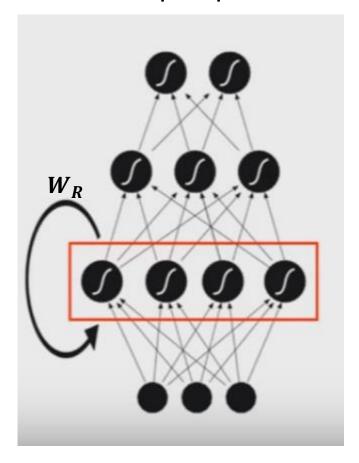
- RNN Introduction
 - Variants on Recurrent nets
 - Training RNN
- Vanishing Gradients and Exploding Gradients
- Proposed Solutions
- Deep Belief Networks
- Memory Systems
 - Gated Recurrent Unit (GRU)
 - Long-Shot Term Memory (LSTM)
- Different Types of Recurrent Memory Models
 - Bi-directional RNN
 - Neural Turing Machine (NTM)
 - Hopfield Neural Networks (HNN)

RNN Introduction

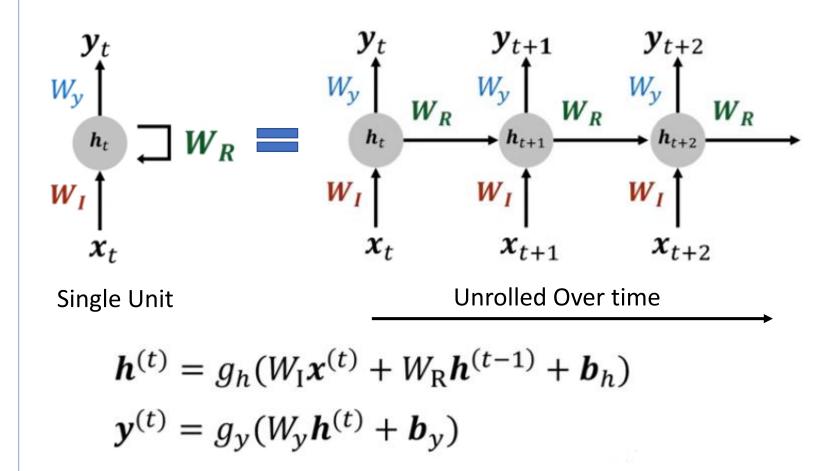
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RNN Introduction

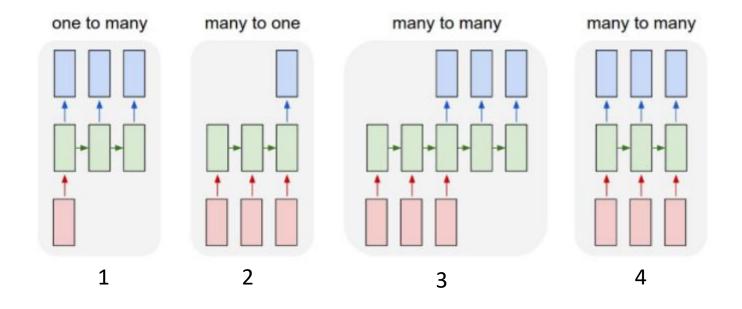
General perspective



If we consider only one single layer Neural Network

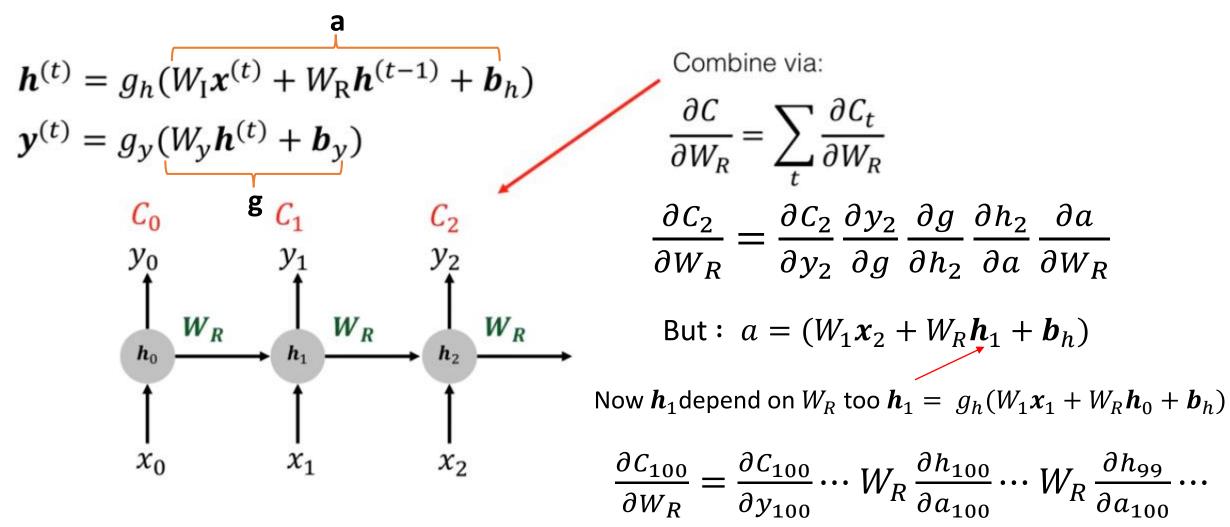


Variants on recurrent nets



- 1: Observe only single time series data and predict few time steps ahead
- 2: Wait for some inputs and give an answer (What's your name? -> Mike)
- 3: This can be use to predict a time series ahead by observing historical time series data (Predicting one month head using previous month data)
- 4 : Online version (Do not wait for a specific amount of input data, Motion tracking of videos)

Training RNN (BPTT – Back Propagation Through Time)



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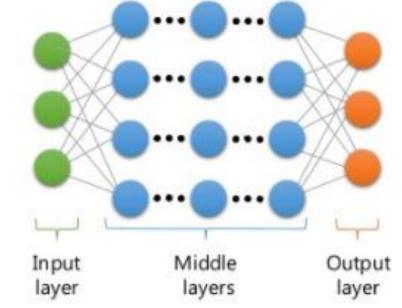
Vanishing and Exploding Gradient

$$h_{t} = W_{R}f(h_{t-1}) + W_{x}x_{t}$$

$$y_{t} = W_{y}f(h_{t})$$

$$\frac{\partial C_{t}}{\partial W_{R}} = \frac{\partial C_{t}}{\partial y_{t}} \frac{\partial y_{t}}{\partial h_{t}} \frac{\partial h_{t}}{\partial h_{k}} \frac{\partial h_{k}}{\partial W_{R}}$$

$$\frac{\partial h_{t}}{\partial h_{k}} = \prod_{i=k+1}^{t} \frac{\partial h_{i}}{\partial h_{i-1}} = W_{R}^{T} diag[f'(\mathbf{h}_{i-1})]$$



Lets if we pick a basis function f and its derivative f' is always bounded by a constant γ_f . Then

$$\left\| \frac{\partial h_i}{\partial h_{i-1}} \right\| \leq \left\| W_R^T \right\| \left\| diag[f'(\boldsymbol{h}_{i-1})] \right\| \leq \gamma_{W_R} \gamma_f$$

$$\left\| \frac{\partial h_t}{\partial h_k} \right\| \le (\gamma_{W_R} \gamma_f)^{t-k}$$

$$\left\| \frac{\partial h_t}{\partial h_k} \right\| \le (\gamma_{W_R} \gamma_f)^{t-k}$$

$$(\gamma_{W_R}\gamma_f)$$
 < 1 \rightarrow Vanishing Gradient $(\gamma_{W_R}\gamma_f)$ \geq 1 \rightarrow Exploding Gradient

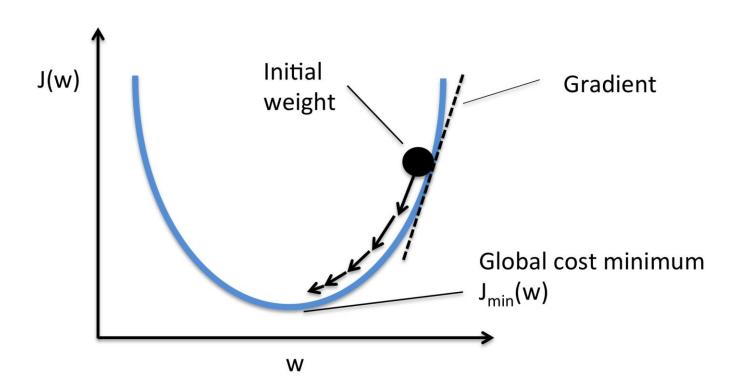
Vanishing and Exploding Gradient will effect in the Gradient update of the learning process

Gradient Descent Algorithm

Repeat until convergence { $W_j = W_j - \alpha \frac{\partial}{\partial W_j} C(y_t, W_j)$ }

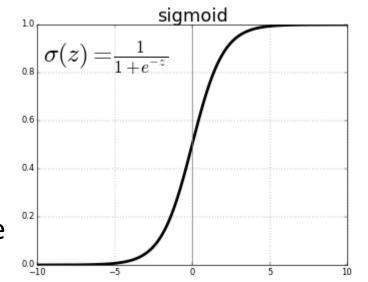
Gradient

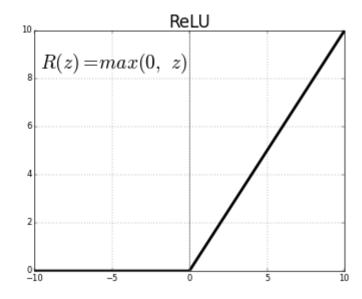
Learning Rate



Proposed solutions

- Exploding Gradients
 - Truncated BPTT
 - Clip Gradients at threshold
 - RMSprop to adjust learning rate



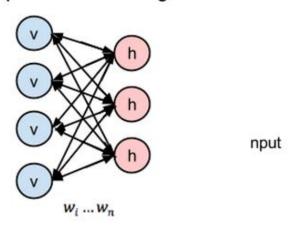


- Vanishing Gradients
 - Weight initialization (Restricted Boltzmann Machine)
 - ReLu activation function (but this can lead to exploding gradient)
 - RMSprop
 - LSTM
 - GRU
- We can set the $\boldsymbol{W_R}$ = 1 , but then we cannot control the learning amount from the past data.

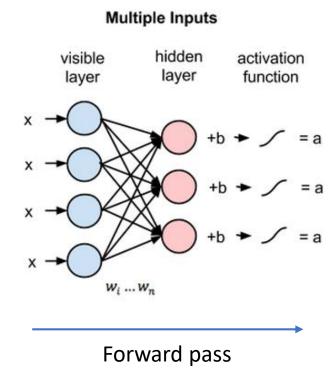
Weight initialization using RBM

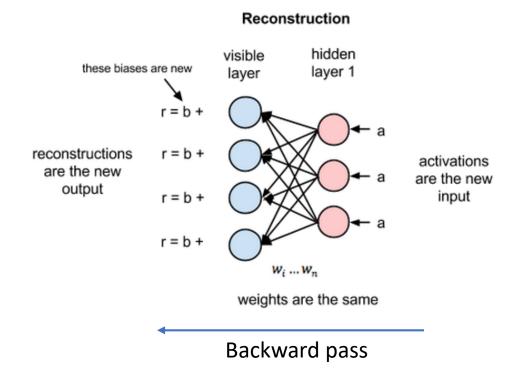
- Use Restricted Boltzmann Machine to pretrain the network
- Pretrain layer by layer and apply the softmax classification
- $CostFuction = ||(Input \ x) (Recreation \ of \ x)||$

A Symmetrical, Bipartite, Bidirectional Graph with Shared Weights



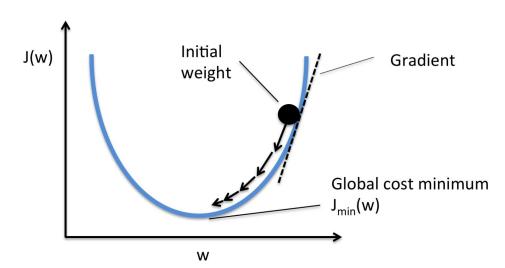
Restricted Boltzmann Machine

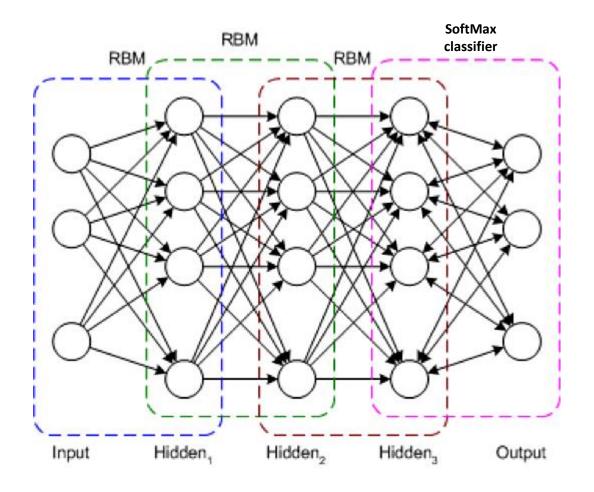




Deep Belief Network

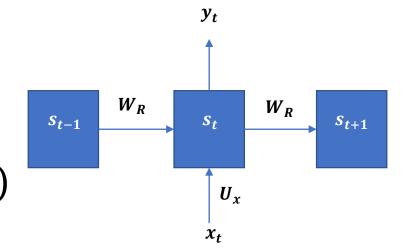
- Use RBM to pretrain the network
- Then it will initialize the weights closer to the global optimal position
- Now since the initializing weights are at a closer place to the optimal position, network will rapidly converge to its cost minimum position





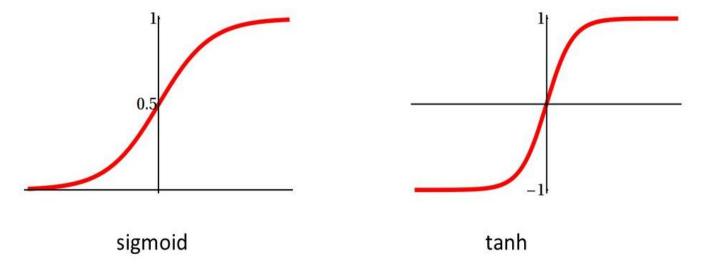
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Memory systems



 $s_t = \varphi(W_R s_{t-1} + U_x x_t + b)$

Nonlinearity is bad for long term memory No selectivity (read all, overwrite all) The RNN memory (state) should be protected only by + or – operations (write to the memory)

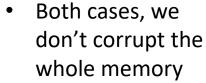


Be selective on choosing, what to read, write and forget

'Write' operation using addition



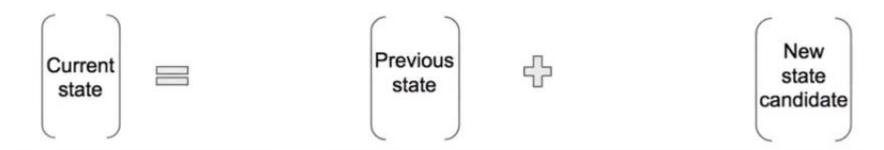
New state candidate is a vector of **positive** numbers



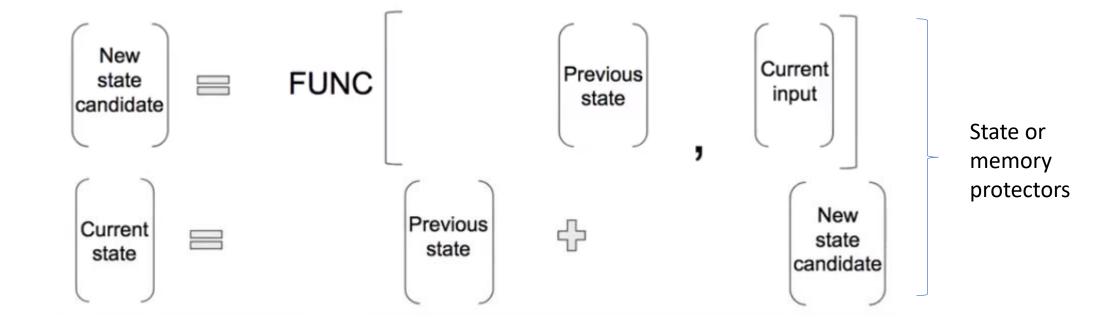
 Just add or subtract something



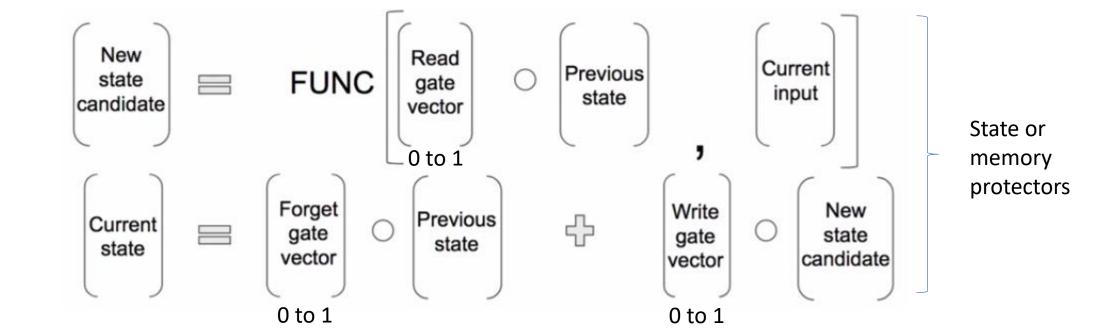
New state candidate is a vector of **negative** numbers



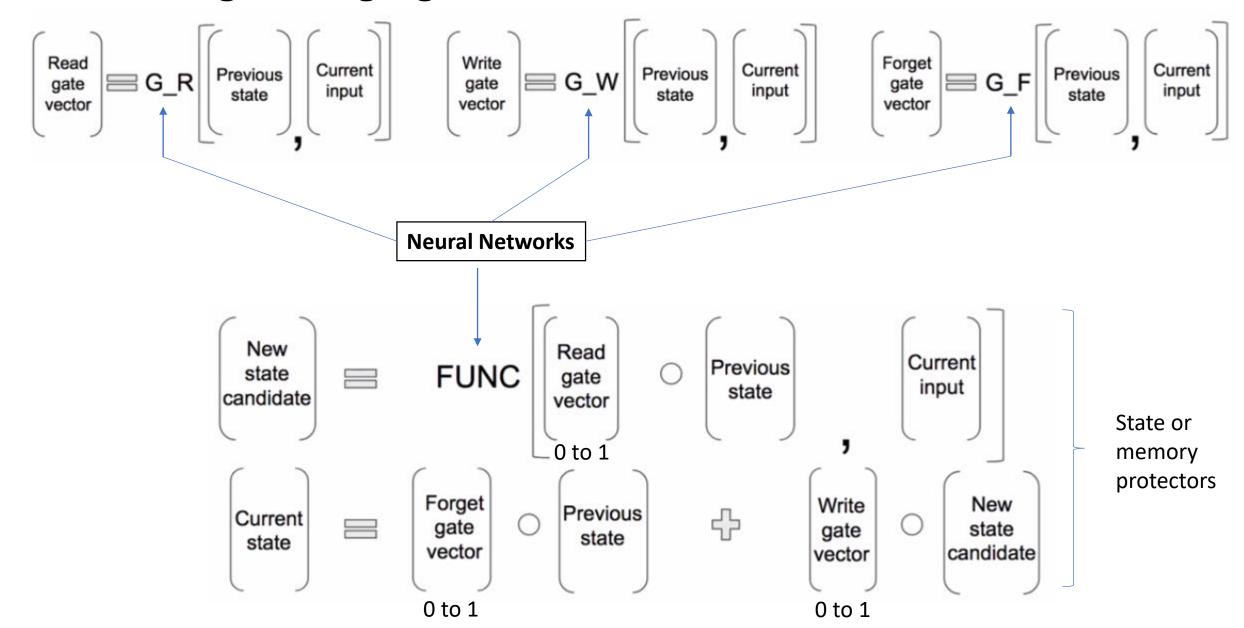
Calculating New State Candidate



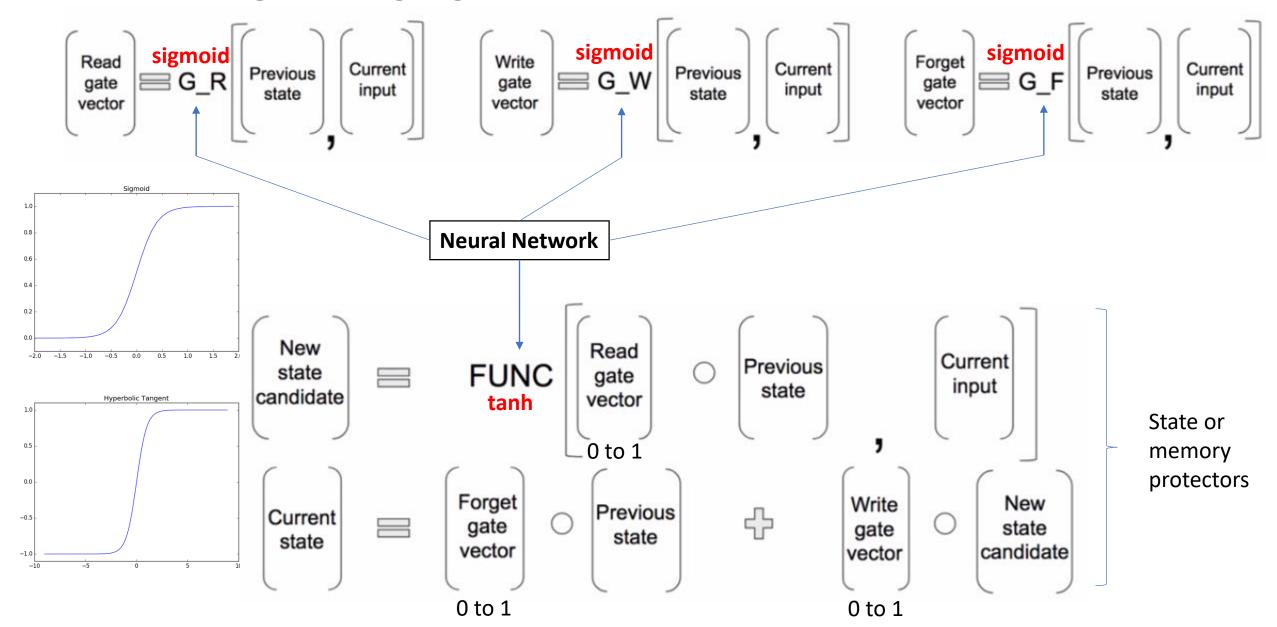
Calculating New State Candidate with selectivity



Selecting through gates



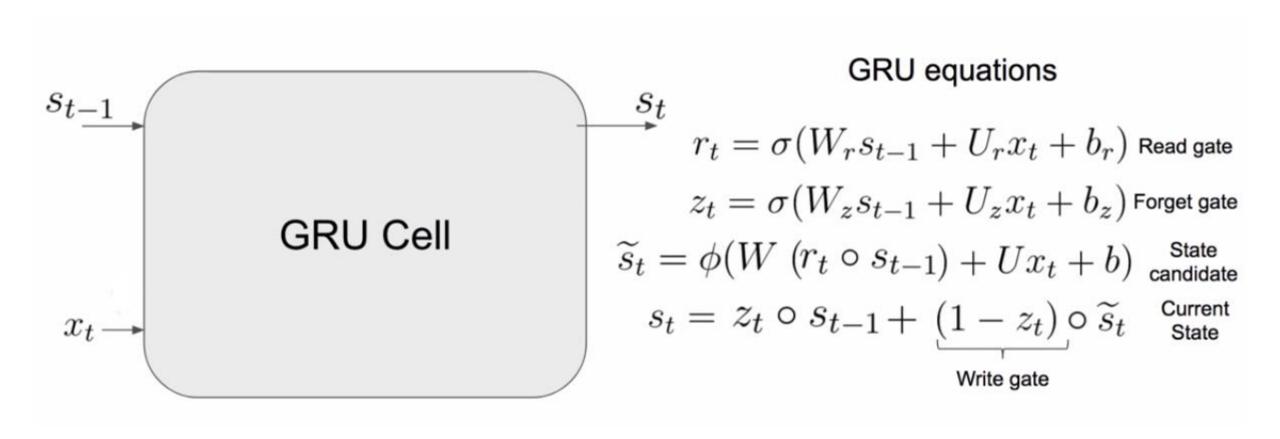
Selecting through gates

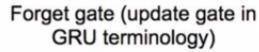


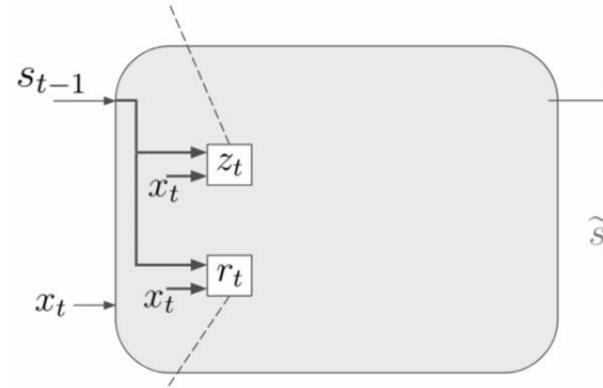
Reasons for activation functions

- Every gate use sigmoid activations in their neural networks
 - Because, gate must be able to control the flow of an incoming stream(memory from previous states)
 - If gate value is 1, then network accept everything which comes from next state
 - If gate value is 0, network will ignore every thing
- Neural network, which predicts the new state candidate uses a tanh activation
 - The new state candidate vector is used in the write operation, therefor both positive and negative values need to be there in the vector
 - If sigmoid is used instead of tanh, then all values will be positive and over flow can be occur

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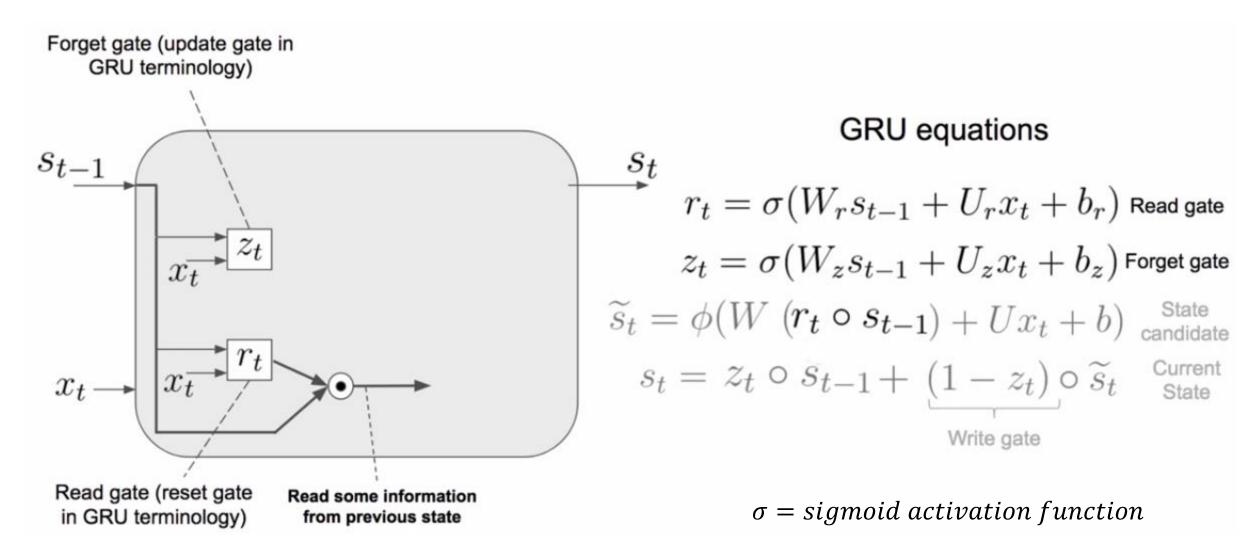
GRU equations

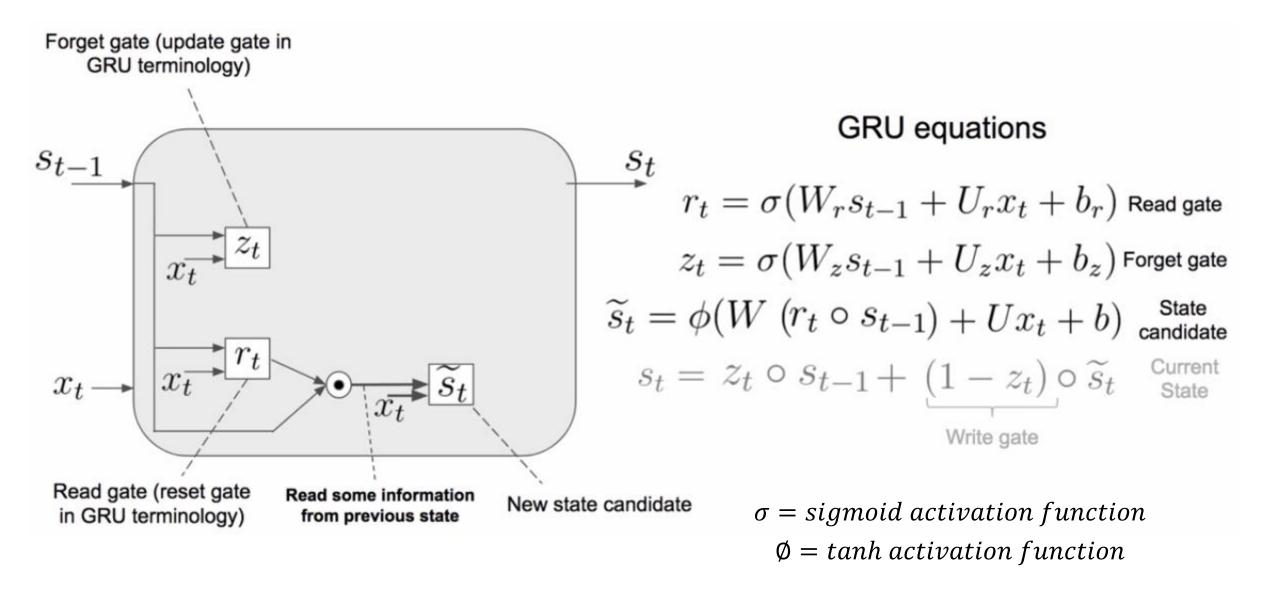
 $T_t = \sigma(W_r s_{t-1} + U_r x_t + b_r) \text{ Read gate}$ $z_t = \sigma(W_z s_{t-1} + U_z x_t + b_z) \text{ Forget gate}$ $\widetilde{s}_t = \phi(W \ (r_t \circ s_{t-1}) + U x_t + b) \text{ State candidate}$ $s_t = z_t \circ s_{t-1} + (1 - z_t) \circ \widetilde{s}_t \text{ Current State}$

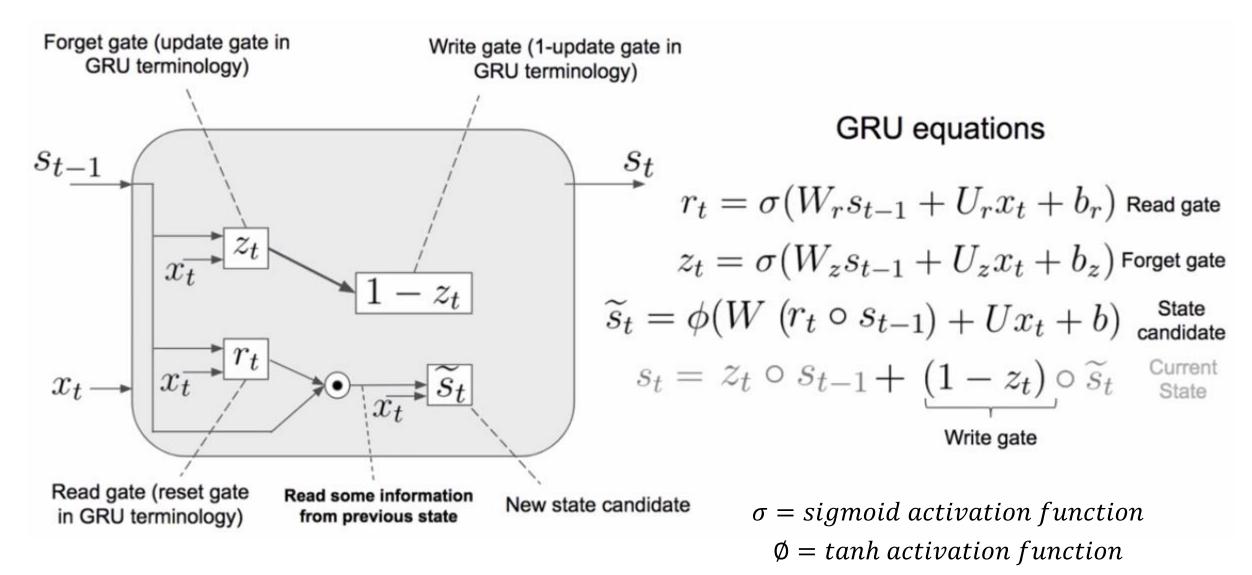
Read gate (reset gate in GRU terminology)

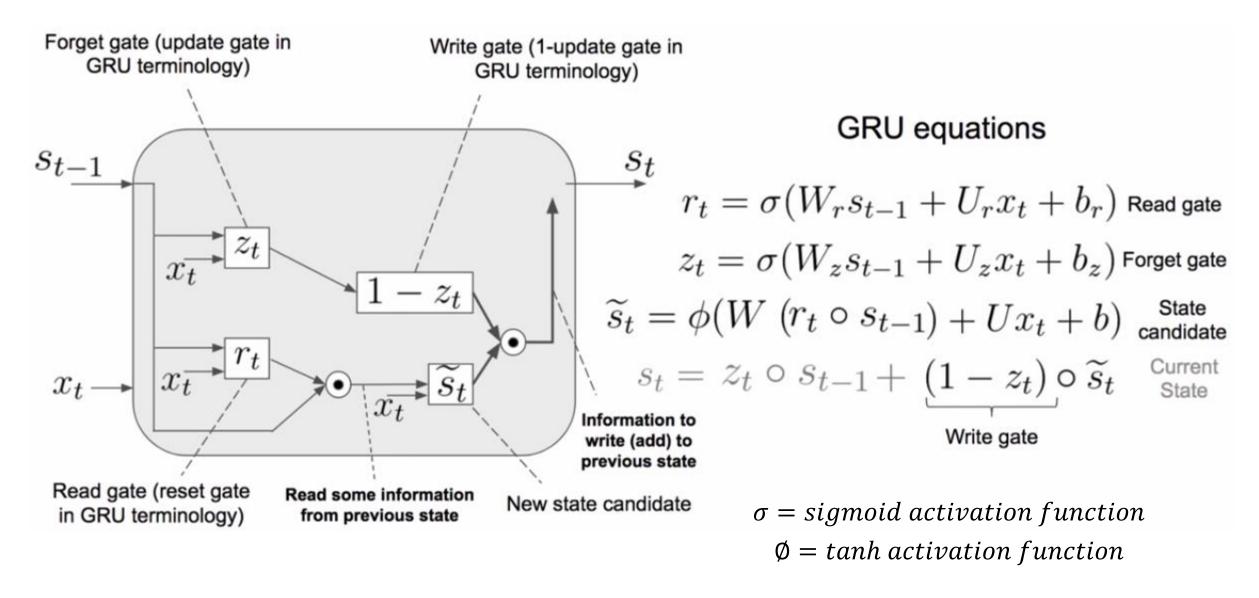
 $\sigma = sigmoid \ activation \ function$

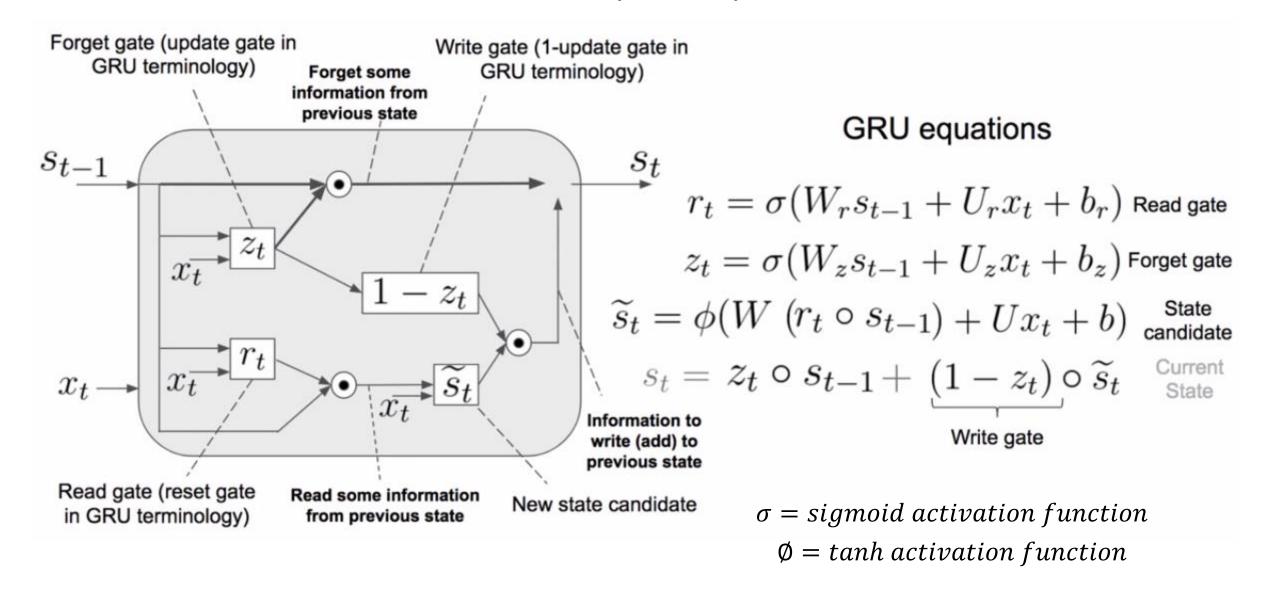
Write gate

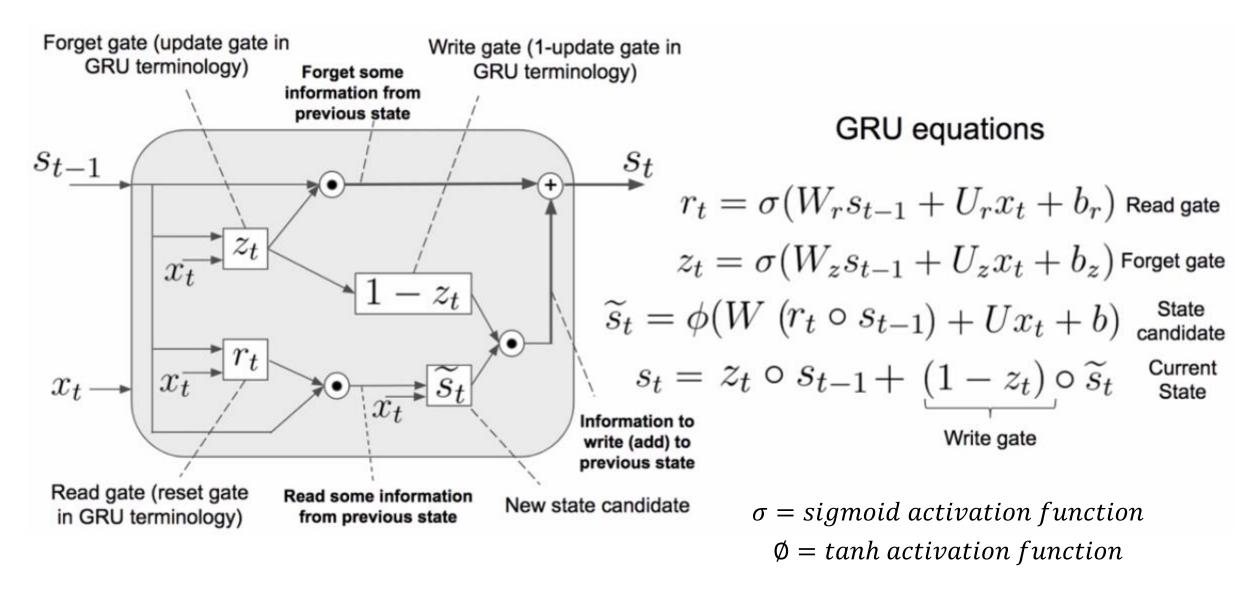


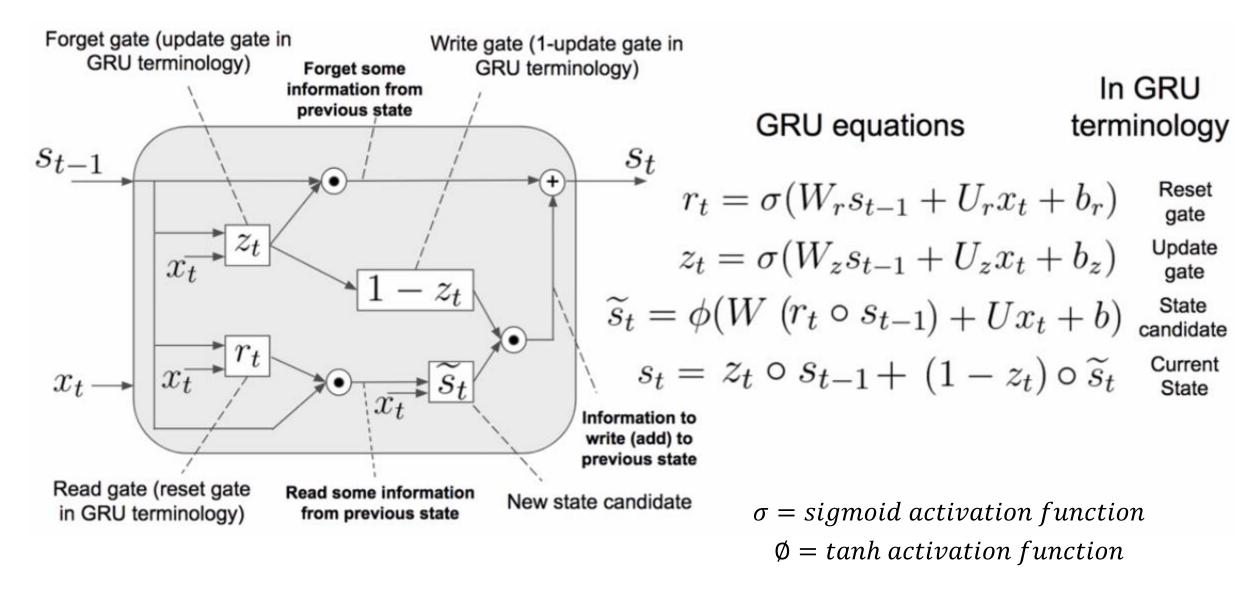












GRU equations

In GRU terminology

$$r_t = \sigma(W_r s_{t-1} + U_r x_t + b_r) \quad \text{Reset} \quad \text{gate} \quad z_t = \sigma(W_z s_{t-1} + U_z x_t + b_z) \quad \text{Update} \quad \text{gate} \quad \widetilde{s}_t = \phi(W \ (r_t \circ s_{t-1}) + U x_t + b) \quad \text{State} \quad \text{candidate} \quad s_t = z_t \circ s_{t-1} + (1-z_t) \circ \widetilde{s}_t \quad \text{Current} \quad \text{State} \quad \text{St$$

Let's take a closer look at the way the gates operate

GRU equations

In GRU terminology

$$\begin{split} r_t &= \sigma(W_r s_{t-1} + U_r x_t + b_r) \quad \underset{\text{gate}}{\text{Reset}} \\ z_t &= \sigma(W_z s_{t-1} + U_z x_t + b_z) \quad \underset{\text{gate}}{\text{Update}} \\ \widetilde{s}_t &= \phi(W \ (r_t \circ s_{t-1}) + U x_t + b) \quad \underset{\text{candidate}}{\text{State}} \\ s_t &= z_t \circ s_{t-1} + (1-z_t) \circ \widetilde{s}_t \quad \underset{\text{State}}{\overset{\text{Current}}{\text{State}}} \\ \begin{pmatrix} \widetilde{s}_t^1 \\ \widetilde{s}_t^2 \\ \widetilde{s}_t^3 \end{pmatrix} = \begin{pmatrix} 0 \\ 0 \\ 0 \\ 0 \end{pmatrix} \circ \begin{pmatrix} s_{t-1}^1 \\ s_{t-1}^2 \\ s_{t-1}^3 \end{pmatrix} + \begin{pmatrix} 1 \\ 1 \\ 1 \\ 0 \end{pmatrix} \circ \begin{pmatrix} \widetilde{s}_t^1 \\ \widetilde{s}_t^2 \\ \widetilde{s}_t^3 \\ \widetilde{s}_t^3 \end{pmatrix} \end{split}$$

Update gate = vector of zeros



Replace all memory content with the State Candidate

GRU equations

In GRU terminology

$$\begin{split} r_t &= \sigma(W_r s_{t-1} + U_r x_t + b_r) \quad \underset{\text{gate}}{\text{Reset}} \\ z_t &= \sigma(W_z s_{t-1} + U_z x_t + b_z) \quad \underset{\text{gate}}{\text{Update}} \\ \widetilde{s}_t &= \phi(W \ (r_t \circ s_{t-1}) + U x_t + b) \quad \underset{\text{candidate}}{\text{State}} \\ s_t &= z_t \circ s_{t-1} + (1-z_t) \circ \widetilde{s}_t \quad \underset{\text{State}}{\overset{\text{Current}}{\text{State}}} \\ \left\langle \begin{array}{c} s_{t-1}^1 \\ s_{t-1}^2 \\ s_{t-1}^3 \\ s_{t-1}^3 \end{array} \right) = \begin{pmatrix} 1 \\ 1 \\ 1 \\ 1 \end{pmatrix} \circ \begin{pmatrix} s_{t-1}^1 \\ s_{t-1}^2 \\ s_{t-1}^3 \\ s_{t-1}^3 \end{pmatrix} + \begin{pmatrix} 0 \\ 0 \\ 0 \\ 0 \end{pmatrix} \circ \begin{pmatrix} \widetilde{s}_t^1 \\ \widetilde{s}_t^2 \\ \widetilde{s}_t^3 \\ \widetilde{s}_t^3 \end{pmatrix} \end{split}$$

Completely ignore current input and state candidate

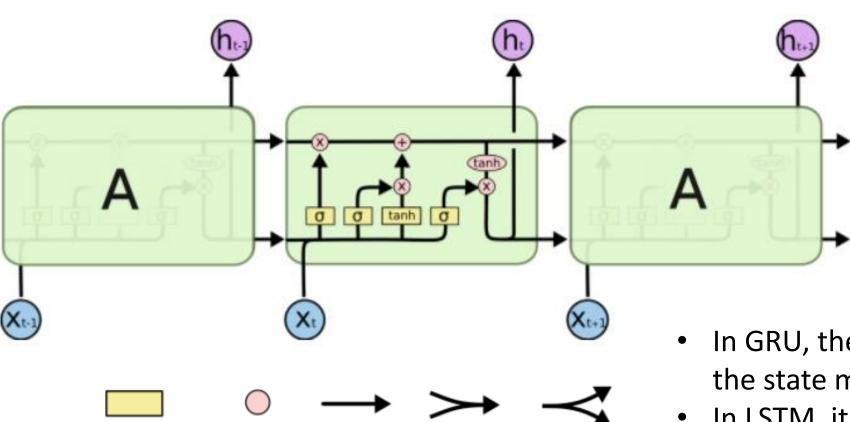
Update gate = vector of ones



The current state equals the previous state

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Long-Shot Term Memory (LSTM)



Concatenate

Neural Network

Layer

Pointwise

Operation

Vector

Transfer

- In GRU, the hidden layer value and the state memory value are the same
- In LSTM, it has a separate state memory flow and a hidden layer value which is gated from the state memory

LSTM Cell

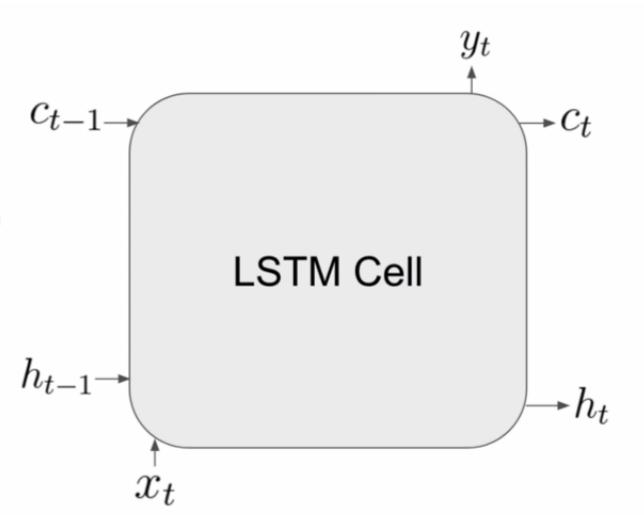
The state is a pair of vectors:

 C_t — Memory Cell

 h_t — Shadow State (gated version of memory cell)

The output is a part of the state:

$$y_t = h_t$$
 — Cell output



LSTM Cell $h_{t-1} \rightarrow$

$$i_t = \sigma(W_i h_{t-1} + U_i x_t + b_i) \text{ Input gate}$$

$$f_t = \sigma(W_f h_{t-1} + U_f x_t + b_f) \text{ Forget gate}$$

$$o_t = \sigma(W_o h_{t-1} + U_o x_t + b_o) \text{ Output gate}$$

$$\widetilde{c}_t = tanh(W h_{t-1} + U x_t + b) \text{ Memory cell candidate}$$

$$c_t = f_t \circ c_{t-1} + i_t \circ \widetilde{c}_t \text{ Memory cell}$$

$$h_t = o_t \circ tanh(c_t) \text{ Shadow state}$$

$$y_t = h_t \text{ Cell Output}$$

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$$y_t = h_t \text{ Cell Output}$$

$-c_t$ x_t Information to write (add) to previous state

$$i_t = \sigma(W_i h_{t-1} + U_i x_t + b_i) \text{ Input gate}$$

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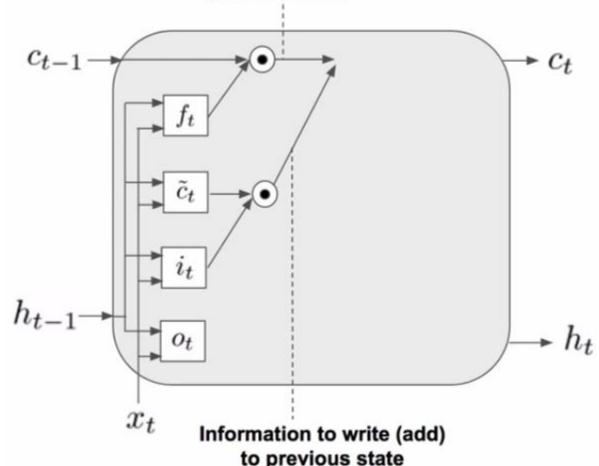
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Forget some information from previous state



$$i_t = \sigma(W_i h_{t-1} + U_i x_t + b_i) \text{ Input gate}$$

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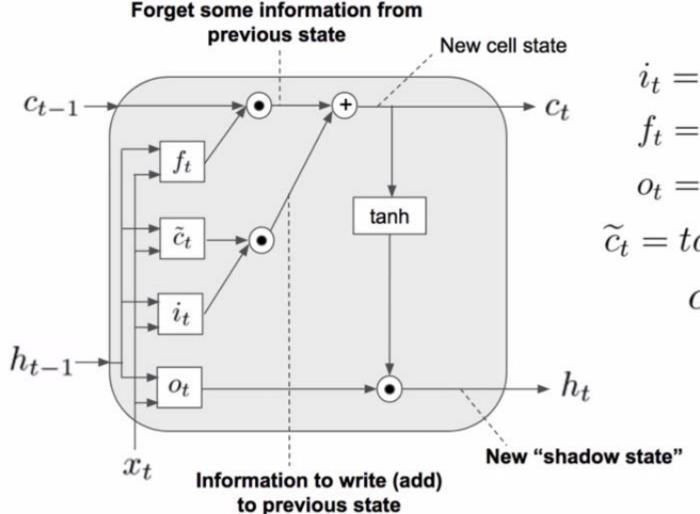
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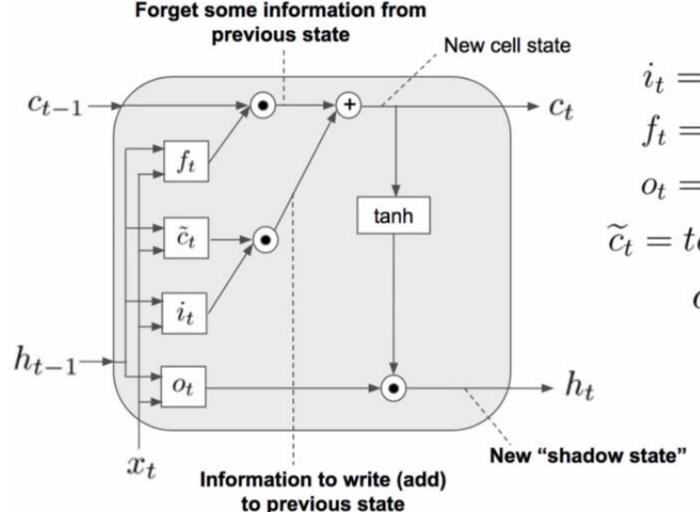
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$$i_t = \sigma(W_i h_{t-1} + U_i x_t + b_i)$$
 Input gate $f_t = \sigma(W_f h_{t-1} + U_f x_t + b_f)$ Forget gate $o_t = \sigma(W_o h_{t-1} + U_o x_t + b_o)$ Output gate $\widetilde{c}_t = tanh(W h_{t-1} + U x_t + b)$ Memory cell candidate $c_t = f_t \circ c_{t-1} + i_t \circ \widetilde{c}_t$ Memory cell $h_t = o_t \circ tanh(c_t)$ Shadow state $y_t = h_t$ Cell Output

Conceptually, we lose information

We use shadow state to calculate gates

LSTM equations

Write gate

$$= \sigma(W, h) + U_{\infty}$$

$$f_t = \sigma(W_f h_{t-1} + U_f x_t + b_f)$$
 Forget gate

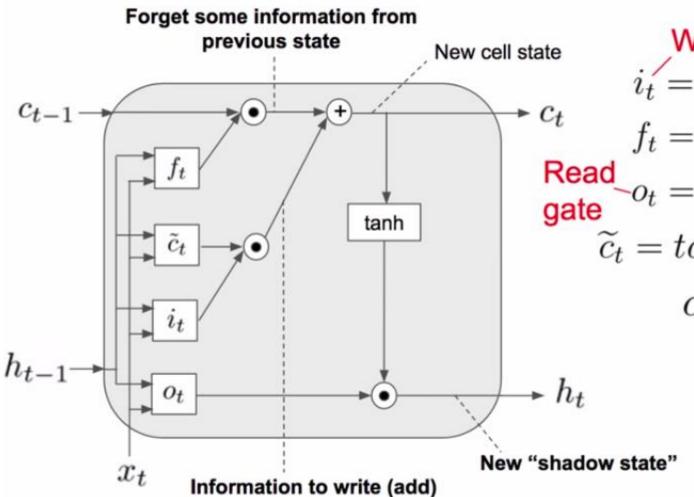
Read $o_t = \sigma(W_o h_{t-1} + U_o x_t + b_o)$ Output gat

$$\widetilde{c}_t = tanh(Wh_{t-1} + Ux_t + b)$$
 Memory cell candidate

$$c_t = f_t \circ c_{t-1} + i_t \circ \widetilde{c}_t$$
 Memory cell

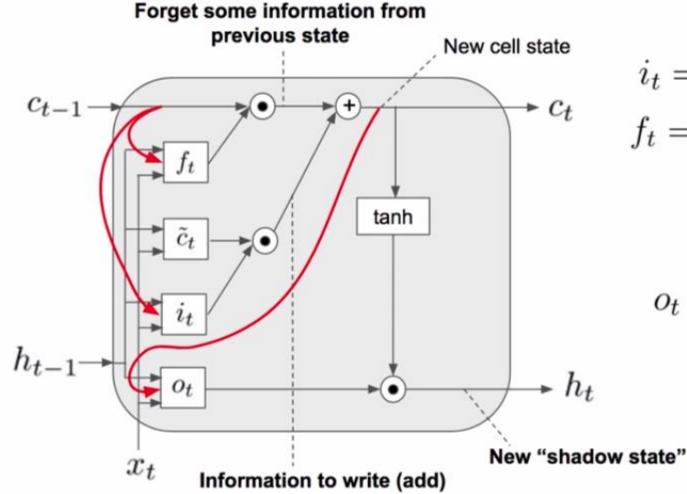
$$h_t = o_t \circ tanh(c_t)$$
 Shadow state $y_t = h_t$ Cell Output

Read occurs after writing



to previous state

LSTM Cell with Peephole connections



to previous state

LSTM with Peephole connections

$$i_{t} = \sigma(W_{i}h_{t-1} + U_{i}x_{t} + P_{i}c_{t-1} + b_{i})$$

$$f_{t} = \sigma(W_{f}h_{t-1} + U_{f}x_{t} + P_{f}c_{t-1} + b_{f})$$

$$\widetilde{c}_{t} = tanh(Wh_{t-1} + Ux_{t} + b)$$

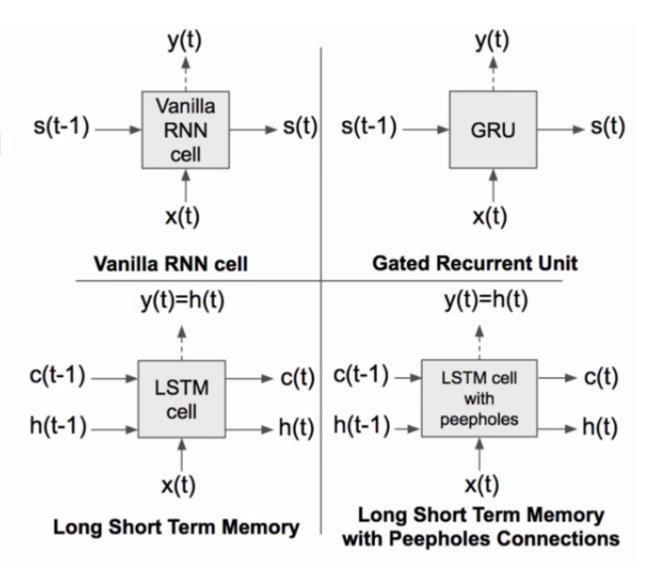
$$c_{t} = f_{t} \circ c_{t-1} + i_{t} \circ \widetilde{c}_{t}$$

$$o_{t} = \sigma(W_{o}h_{t-1} + U_{o}x_{t} + P_{o}c_{t} + b_{o})$$

$$h_{t} = o_{t} \circ tanh(c_{t})$$

$$y_{t} = h_{t}$$

- LSTM and GRU are the most widely used cells in production systems and to achieve state of the art
- GRU cell, perhaps, is the most intuitive one
- LSTM with Peephole connections was designed to attack potential loss of information of Basic LSTM cell



Vanilla RNN

Late 1980s - backpropagation through time to train Vanilla RNN

LSTM

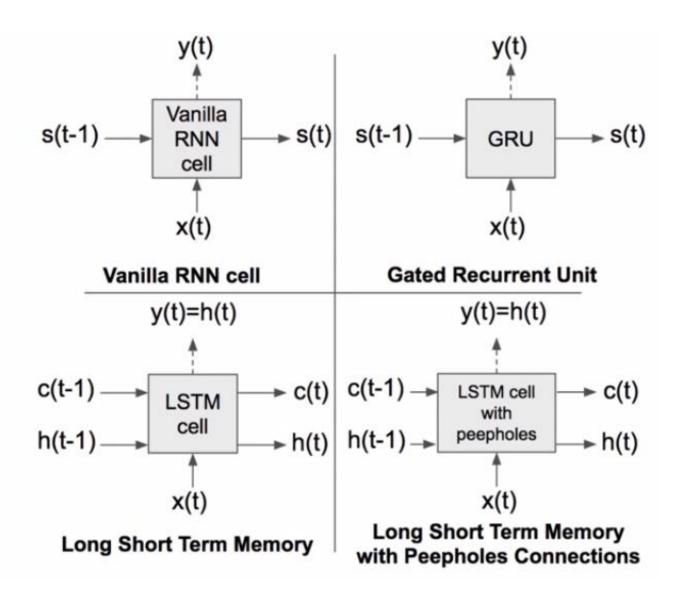
1997 - Long Short-Term Memory (S.Hochreiter, J.Schmidhuber)

LSTM with Peepholes

2000 - Recurrent nets that time and count (F.A. Gers; J. Schmidhuber)

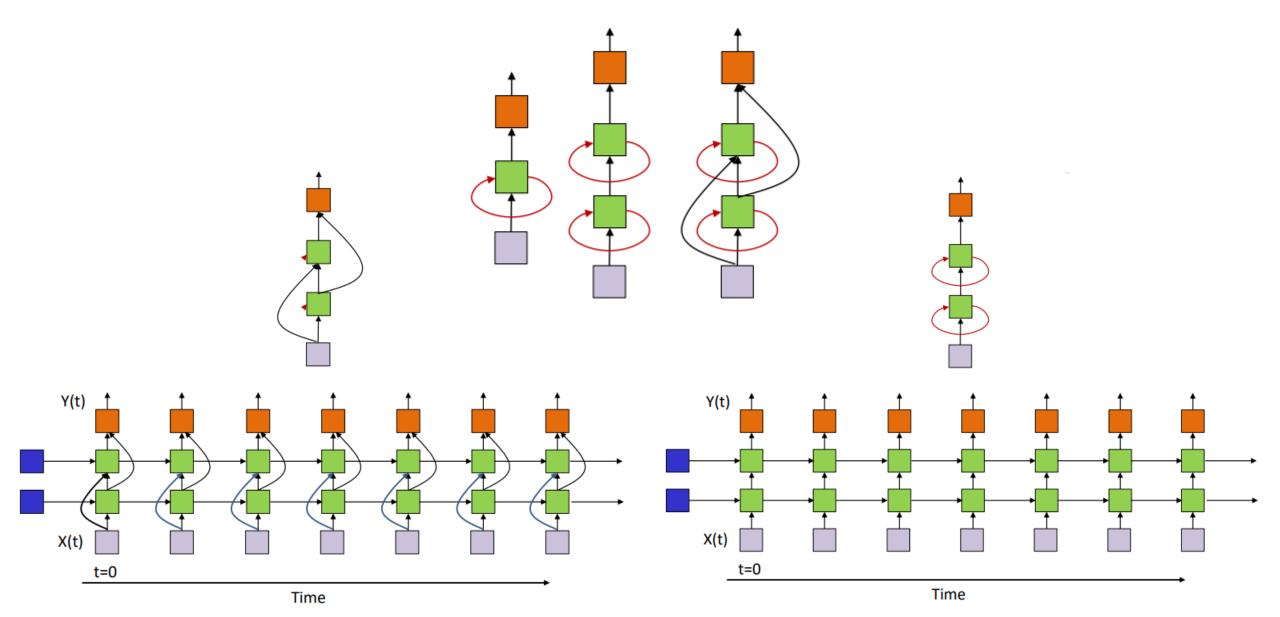
GRU

2014 - Learning Phrase Representations using RNN Encoder–Decoder for Statistical Machine Translation (Kyunghyun Cho, Yoshua Bengio, and others)

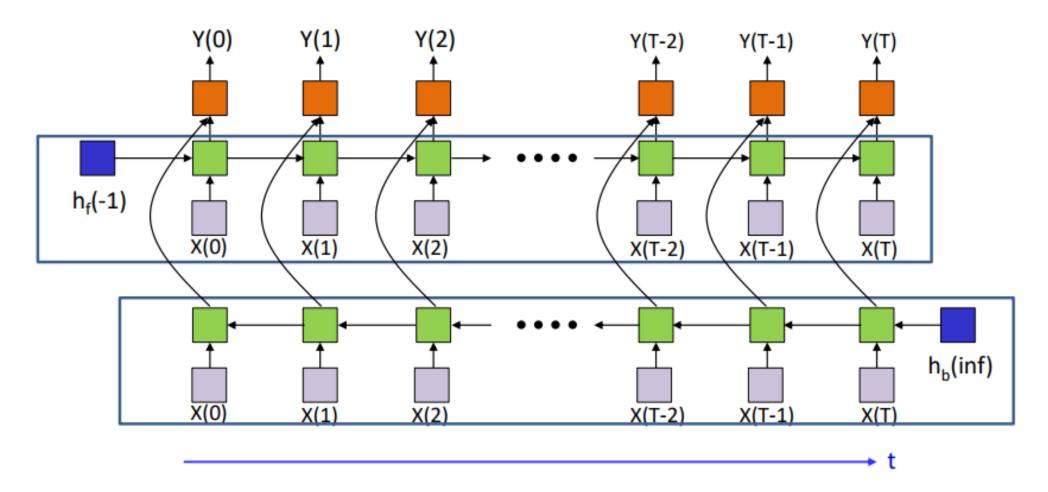


- RNN Introduction
 - Variants on Recurrent nets
 - Training RNN
- Vanishing Gradients and Exploding Gradients
- Proposed Solutions
- Deep Belief Networks
- Memory Systems
 - Gated Recurrent Unit (GRU)
 - Long-Shot Term Memory (LSTM)
- Different Types of Recurrent Memory Models
 - Bi-directional RNN
 - Neural Turing Machine (NTM)
 - Hopfield Neural Networks (HNN)

Different types of Recurrent Memory models



Bi-directional RNN



- A forward net process the data from t=0 to t=T
- A backward net processes it backward from t=T down to t=0

Neural Turing Machines

Alex Graves

gravesa@google.com

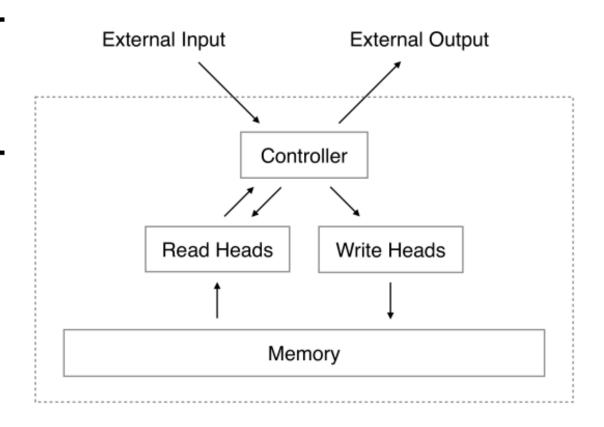
Greg Wayne

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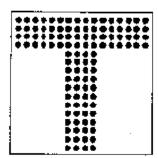
Google DeepMind, London, UK



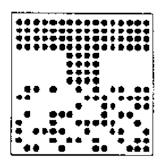
Two criticisms were answered against Neural networks

- neural networks with fixed-size inputs are seemingly unable to solve problems with variable-size inputs
- neural networks seem unable to bind values to specific locations in data structures. This
 ability of writing to and reading from memory is critical in the two information processing
 systems we have available to study: brains and computers

Hopfield Networks

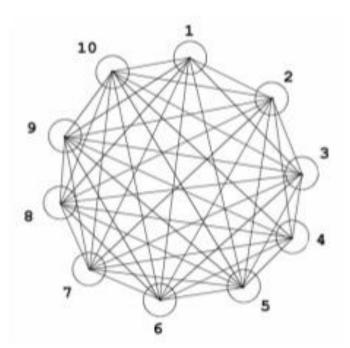


Original 'T'



half of image corrupted by noise

- Sub-type of recurrent neural nets
 - Fully recurrent
 - Weights are symmetric
 - Nodes can only be on or off
 - Random updating
- Learning: Hebb rule (cells that fire together wire together)
- Can recall a memory, if presented with a corrupt or incomplete version
 - → auto-associative or content-addressable memory



Thank You